

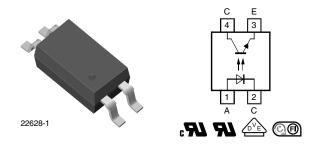
COMPLIANT



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# Optocoupler, Phototransistor Output, Single Channel, Half Pitch Mini-Flat Package



#### **DESCRIPTION**

The TCMT110. series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

### **FEATURES**

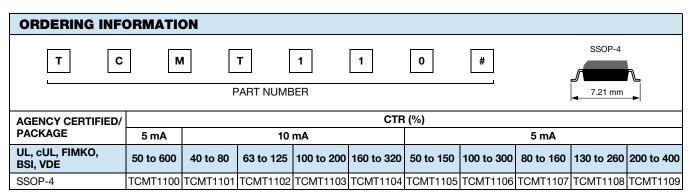
- Low profile package (half pitch)
- AC isolation test voltage 3750 V<sub>RMS</sub>
- · Low coupling capacitance of typical 0.3 pF
- · Current transfer ratio (CTR) selected into groups
- · Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



- Programmable logic controllers
- Modems
- Answering machines
- General applications

#### **AGENCY APPROVALS**

- UL1577, file no. E76222, double protection
- cUL component acceptance service no. 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5)
- FIMKO: FI EN 60950-1:2006
- BSI: BS EN60065:2002 BS EN60950-1:2006
- CQC GB 8898-2011, GB 4943.1-2011 (suitable for installation altitude below 2000 m)



#### Note

· Available only on tape and reel.



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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V <sub>R</sub>	6	V
Forward current		I <sub>F</sub>	60	mA
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	Α
Power dissipation		P <sub>diss</sub>	100	mW
Junction temperature		Tj	125	°C
ОИТРИТ				
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		Ic	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation		P <sub>diss</sub>	150	mW
Junction temperature		Tj	125	°C
COUPLER				
AC isolation test voltage (RMS)	Related to standard climate 23/50 DIN 50014	V <sub>ISO</sub>	3750	V <sub>RMS</sub>
Total power dissipation		P <sub>tot</sub>	250	mW
Operating ambient temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 125	°C
Soldering temperature (1)		T <sub>sld</sub>	260	°C

#### Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	$I_F = 50 \text{ mA}$	V <sub>F</sub>		1.35	1.6	V	
Junction capacitance	$V_R = 0$ , $f = 1$ MHz	C <sub>j</sub>		8		pF	
OUTPUT	OUTPUT						
Collector emitter voltage	I <sub>C</sub> = 100 μA	$V_{CEO}$	70			V	
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I <sub>CEO</sub>			100	nA	
COUPLER	COUPLER						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V <sub>CEsat</sub>			0.3	V	
Cut-off frequency	$V_{CE}$ = 5 V, $I_F$ = 10 mA, $R_L$ = 100 $\Omega$	f <sub>c</sub>		100		kHz	
Coupling capacitance	f = 1 MHz	C <sub>k</sub>		0.3		pF	

### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



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# TCMT110. Series

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CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCMT1100	CTR	50		600	%	
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA	TCMT1101	CTR	40		80	%	
		TCMT1102	CTR	63		125	%	
		TCMT1103	CTR	100		200	%	
1-/1-		TCMT1104	CTR	160		320	%	
I <sub>C</sub> /I <sub>F</sub>	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 5 mA	TCMT1105	CTR	50		150	%	
		TCMT1106	CTR	100		300	%	
		TCMT1107	CTR	80		160	%	
		TCMT1108	CTR	130		260	%	
		TCMT1109	CTR	200		400	%	

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see figure 1)}$	t <sub>d</sub>		4.0		μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ , (see figure 1)	t <sub>r</sub>		5.5		μs
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see figure 1)}$	t <sub>f</sub>		7.0		μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see figure 1)}$	ts		1.5		μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see figure 1)}$	t <sub>on</sub>		9.5		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see figure 1)}$	t <sub>off</sub>		8.5		μs
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ , (see figure 2)	t <sub>on</sub>		3.0		μs
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega, \text{ (see figure 2)}$	t <sub>off</sub>		20.0		μs

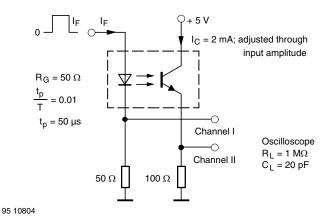


Fig. 1 - Test Circuit, Non-Saturated Operation

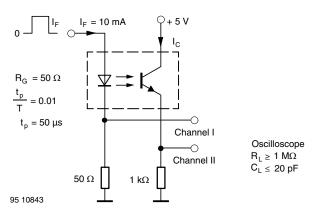


Fig. 2 - Test Circuit, Saturated Operation

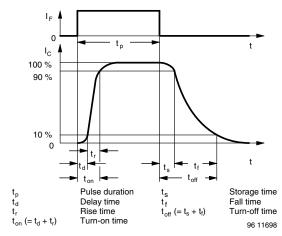


Fig. 3 - Switching Times

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SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification (according to IEC 68 part 1)			40/110/21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	t = 1 min	V <sub>ISO</sub>	3750	V <sub>RMS</sub>
Maximum transient isolation voltage		V <sub>IOTM</sub>	6000	V
Maximum repetitive peak isolation voltage		$V_{IORM}$	707	V
Apparent charge test voltage (method A)	$V_{IORM}$ x 1.6 = $V_{PR}$ , type and sample test, t <sub>m</sub> = 60 s, partial discharge < 5 pC	$V_{PR}$	1132	V <sub>peak</sub>
Apparent Charge Test Voltage (method B)	$V_{IORM}$ x 1.875 = $V_{PR}$ , 100 % production test with $t_m$ = 1 s, partial discharge < 5 pC	$V_{PR}$	1326	V <sub>peak</sub>
Isolation resistance	V <sub>IO</sub> = 500 V <sub>DC</sub> , T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	10 <sup>11</sup>	Ω
Isolation resistance (under fault conditions)	$V_{IO} = 500 V_{DC}, T_{amb} = T_{SI}$	R <sub>IO</sub>	10 <sup>9</sup>	Ω
Output safety power		P <sub>SO</sub>	350	mW
Input safety current		I <sub>SI</sub>	150	mA
Input safety temperature		T <sub>SI</sub>	175	°C

#### Note

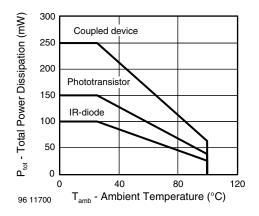
As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Creepage distance			5			mm	
Clearance distance			5			mm	
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm	

#### Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)





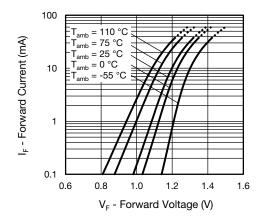


Fig. 5 - Forward Voltage vs. Forward Current



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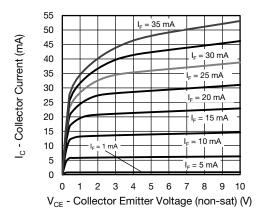


Fig. 6 - Collector Current vs. Collector Emitter Voltage

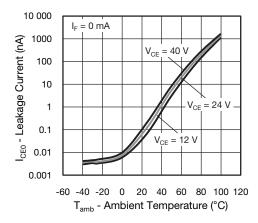


Fig. 7 - Leakage Current vs. Ambient Temperature

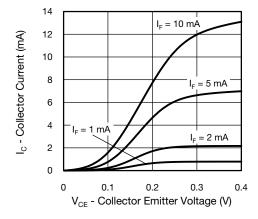


Fig. 8 - Collector Current vs. Collector Emitter Voltage

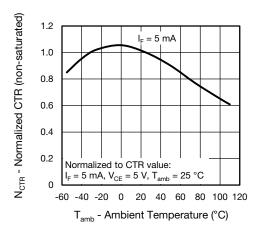


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

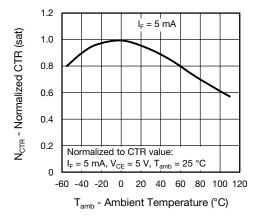


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

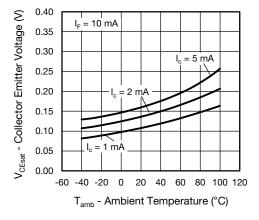


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

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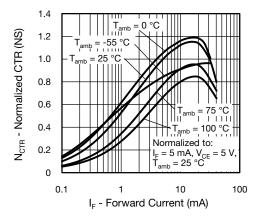


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current

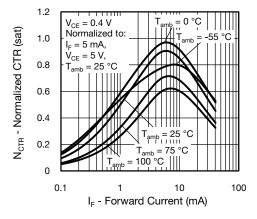


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

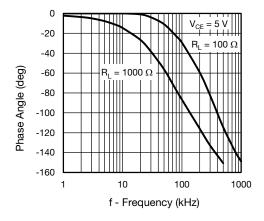


Fig. 14 -  $F_{CTR}$  vs. Phase Angle

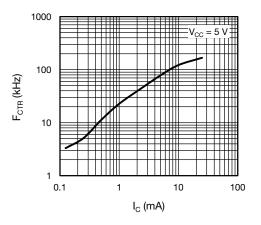


Fig. 15 - F<sub>CTR</sub> vs. Collector Current

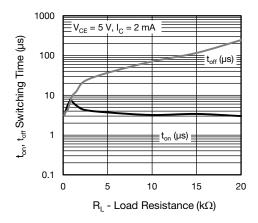


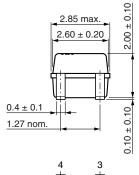
Fig. 16 - Switching Time vs. Load Resistance

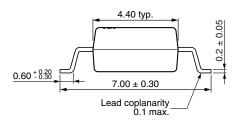


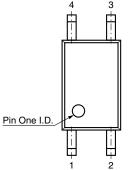
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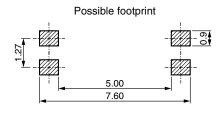
### **PACKAGE DIMENSIONS** in millimeters

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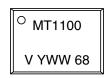




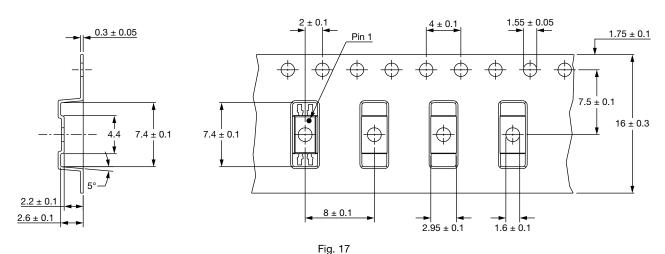




### **PACKAGE MARKING** (example)



#### TAPE AND REEL PACKAGING in millimeters





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### **SOLDER PROFILES**

#### 300 max. 260 250 -240 °C -217 °C Temperature (°C) 200 max. 30 s 150 max. 120 s max. 100 s 100 max. ramp down 6 °C/s 50 nax. ramp up 3 °C/s 0 50 100 150 200 250 300 Time (s)

Fig. 18 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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